



Call for papers

Papers are invited in the area of Micro/Nanoelectronics, Semiconductor Materials, Devices, Circuits and Systems focused on the emerging areas such as: Advanced Logic Technology; Emerging Devices & Compute Technology; Memory Technology; Microwave, Millimeter Wave & Analog Technology; Modeling and Simulation; Optoelectronics, Displays, and Imaging Systems; Power Devices and Systems; Reliability of Systems and Devices; Sensors, MEMS, and Bioelectronics; Analog, Digital, Mixed-Signal IC Design; Embedded and FPGA based Systems design, etc. in the following conference tracks:

Micro/Nanoelectronics Devices: Device Physics, Quantum Electronics, Quantum Transport, Compact Device Modelling, LED, MOSFET, MESFET, FinFET, TFET, Beyond CMOS, III-V HEMT, Ga₂O₃ HEMT, SET, UWB Semiconductor Materials and Devices, 2D Materials: Graphene, Spintronics, Carbon Nanotubes.

Nanotechnology: Nanowires, Nanostructures, Flexible Electronics, High Efficiency Solar Cells, Novel Photovoltaic Concepts, Energy Storage, Advanced Energy Materials, Advanced Electronic Devices, Advanced Interconnects, Optoelectronics and Photonics etc.

Micro/Nanoelectronics Circuits: Analog VLSI Circuits, Digital VLSI Circuits, Mixed-mode VLSI Circuits, System on Chip (SoC), Bio-electronics Circuits, Circuit Optimization Techniques, Reconfigurable Circuits, HDL based FPGA Design, Testing and Verification, Packaging, Circuit Reliability, DSP based VLSI etc.

Micro/Nano Systems: MEMS/NEMS, Sensors, Actuators, Nanogenerator, Energy Harvester, Micromachining, Microfluidics, Lab-on-Chip, Health Care Systems, Embedded System Design, Biomedical Systems, IoT/IoE and Smart Systems, Robotics and Mechatronics, MEMS Packaging, System Reliability, Semiconductor Memories etc.

Important dates

Full Paper Submission in Springer LNEE Proceedings: Oct. 15, 2024
Format available online at:

<https://www.springer.com/us/authors-editors/conference-proceedings>

Notification of Acceptance: Dec. 31, 2024

Revised Paper Submission: Jan. 15, 2025

Highlights

- Keynote Talks (12+) From International/ National Experts and peer networking.
- Oral Presentations and Posters (50+).
- Industry Sessions and Industry Exhibition.
- Accepted & presented papers to be published in Springer LNEE.

Dr. Kavicharan Mummaneni

Assistant Professor
NIT Silchar, Dept. of ECE
kavicharan@ece.nits.ac.in

Dr. Rajesh Saha

Assistant Professor
NIT Silchar, Dept. of ECE
rajesh@ece.nits.ac.in

Dr. Dipjyoti Das

Assistant Professor
NIT Silchar, Dept. of ECE
dipjyoti@ece.nits.ac.in

5th International Conference on

Micro/Nanoelectronics Devices, Circuits, & System (MNDCS-2025)

29-31 JAN

Hybrid mode

About the Conference

The 5th edition of Micro/Nanoelectronics Devices, Circuits, and Systems MNDCS-2025 is scheduled during **29-31 Jan, 2025** in Hybrid Mode at *National Institute of Technology (NIT) Silchar, Department of Electronics and Communication (ECE), Silchar, Assam, India* in association with **IEEE EDS NIT Silchar Student Branch Chapter** and **IEEE Nanotechnology Council Chapter**. The objective of MNDCS 2025 is to promote advanced research and developments in the areas of Micro/Nanoelectronics, Semiconductor Materials and Devices, VLSI Circuits and Systems. The conference aims to foster the theme through keynotes, invited talks, and oral/poster presentations of research articles in the most relevant areas allied to the theme of the conference. It'll also create an international platform to share research ideas, scientific thoughts and research problems among academicians, researchers, technologists and scientists.

Submission Guidelines

- Papers submission link:
<https://cmt3.research.microsoft.com/MNDCS2025>
- The peer-reviewed and selected papers of the conference would be published in Scopus indexed Springer conference proceedings in "Lecture Notes in Electrical Engineering (LNEE)" series:
<https://www.springer.com/series/7818>.
- Top quality papers will be published in MDPI Sensors Journal (SCI) and Microsystem Technologies Journal (SCI)





5th International Conference on Micro/Nanoelectronics Devices, Circuits, & System (MNDCS-2025)

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Invitation to review submission for Micro/Nanoelectronics Devices, Circuits, & Systems

2 messages

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Tue, Jan 7, 2025 at 6:40 PM

Reply-To: "Dr. Kavicharan Mummaneni" <kavicharan@ece.nits.ac.in>

To: Souvik Bhanja <souvik.bhanja23@gmail.com>

Cc: kavicharan.phd@gmail.com

Greetings from NIT Silchar.

We congratulate you on the acceptance of your paper ID: 52 of title: **Exploring the Sensing Ability of Pristine and Ag-Doped WS₂ for Colon Cancer Biomarkers: A First-Principles Study** for oral presentation at MNDCS-2025 and possible inclusion in the conference proceedings.

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Souvik Bhanja <souvik.bhanja23@gmail.com>
To: soubarnochatterjee2002@gmail.com

Tue, Jan 7, 2025 at 6:51 PM

[Quoted text hidden]

Exploring the Sensing Ability of Pristine and Ag-Doped WS₂ for Detection of Colon Cancer Biomarkers: A First-Principles Study

Indranil Maity¹[0000-0002-4919-3072], Soubarno Chatterjee¹[0009-0007-2682-1535]
and Souvik Bhanja¹[0009-0005-2428-783X]

¹ Department of Electronics and Communication Engineering (ECE), Institute of Engineering and Management (IEM), Kolkata, West Bengal, India

indrasanu026@gmail.com

Abstract. Colon cancer is one of the most common causes for cancer-related deaths all over the world. This fact alone highlights the necessity for the early detection of colon cancer in order to reduce the mortality rate. This research work explored the detection ability of pristine tungsten disulfide (WS₂) and Ag-doped tungsten disulfide (WS₂) towards cyclohexanone, which is one of the major biomarkers of colon cancer (present in a human exhaled breath), via first-principles-based calculations. Gaussian 09W and GaussView 6.0 software packages have been employed to obtain different adsorption properties. After the geometry optimization of both pristine WS₂ and Ag-doped WS₂, cyclohexanone was introduced to observe the sensing performance and mechanism of the cyclohexanone-adsorbed pristine WS₂ (P-WS₂), and the cyclohexanone-adsorbed Ag-doped WS₂ (Ag-WS₂) system. Different sensing parameters were obtained from the structures, e.g., ESP (Electrostatic Potential), Mulliken charges, DOS (Density of States), PDOS (Partial Density of States), band structure, adsorption energy, and binding distance. Electrostatic potential indicates the possible sites for nucleophilic attack (electrophilic reactivity), and electrophilic attack (nucleophilic reactivity). The band structure plots revealed that the Ag-doped WS₂ was more semi-metallic than pristine WS₂. The binding distance and adsorption energy values also helped to figure out, which sensing material is more efficient. The entropy and Gibbs free energy values were calculated with respect to different temperatures, and it was observed that Ag-doped WS₂ is more favorable for sensing of cyclohexanone. Overall, studies of these physiochemical parameters provided clear understanding about the underlying sensing mechanism and improved the quality of the potential gas/vapor sensor.

Keywords: Colon Cancer, Exhaled Breath Analysis, Tungsten Disulfide, Cyclohexanone Adsorption, Thermodynamic Study.

1 Introduction

Colon cancer, also known as colorectal cancer, is one of the most frequently occurring cancer, which causes a significant number of deaths. The risk of getting affected by this cancer gets higher as one's age crosses forties [1]. It is also known that family history

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